International **ICR** Rectifier

HEXFRED[™]

Features

- · Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- · Specified at Operating Conditions **Benefits**
- · Reduced RFI and EMI
- · Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- · Reduced Parts Count

Description

International Rectifier's HFA25TB60S is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 25 amps continuous current, the HFA25TB60S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA25TB60S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

	Parameter	Max.	Units
V _R	Cathode-to-Anode Voltage	600	V
I _F @ T _C = 100°C	Continuous Forward Current	25	
I _{FSM}	Single Pulse Forward Current	225	Α
I _{FRM}	Maximum Repetitive Forward Current	100	
P _D @ T _C = 25°C	Maximum Power Dissipation	125	w
P _D @ T _C = 100°C	Maximum Power Dissipation	50	~ ~
TJ	Operating Junction and	55 to 1450	°C
T _{STG}	Storage Temperature Range	-55 to +150	

Absolute Maximum Ratings

* 125°C

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HFA25TB60S

Ultrafast, Soft Recovery Diode

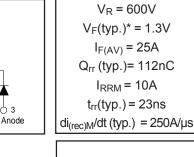
Base Cathode

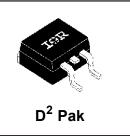
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Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
V _{BR}	Cathode Anode Breakdown Voltage	600			V	I _R = 100μA	
V _{FM}	Max Forward Voltage		1.3	1.7	V	I _F = 25A	
			1.5	2.0		I _F = 50A See Fig. 1	
			1.3	1.7		I _F = 25A, T _J = 125°C	
I _{RM}	Max Reverse Leakage Current		1.5	20	μA	$V_R = V_R$ Rated See Fig. 2	
			600	2000	μΛ	T_J = 125°C, V_R = 0.8 x V_R Rated	
CT	Junction Capacitance		55	100	pF	V _R = 200V See Fig. 3	
	Carias Industance		8.0		nH	Measured lead to lead 5mm from	
LS	Series Inductance					package body	

Dynamic Recovery Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified	Dynamic Recovery	Characteristics	@ T _J = 25°C (unless	s otherwise specified)
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	Parameter	Min.	Тур.	Max.	Units	Test Conditions		
t _{rr}	Reverse Recovery Time		23			I_F = 1.0A, di _f /dt = 200A/µs, V _R = 30V		
t _{rr1}	See Fig. 5		50	75	ns	T _J = 25°C		
t _{rr2}			105	160		T _J = 125°C	I _F = 25A	
I _{RRM1}	Peak Recovery Current		4.5	10		T _J = 25°C		
I _{RRM2}	See Fig. 6		8.0	15	A	T _J = 125°C	V _R = 200V	
Q _{rr1}	Reverse Recovery Charge		112	375		T _J = 25°C		
Q _{rr2}	See Fig. 7		420	1200	nC	T _J = 125°C	di _f /dt = 200A/µs	
di _{(rec)M} /dt1	Peak Rate of Fall of Recovery Current		250		A /	T _J = 25°C		
di _{(rec)M} /dt2	During t _b See Fig. 8		160		A/µs	T _J = 125°C		

Thermal - Mechanical Characteristics

	Parameter	Min.	Тур.	Max.	Units
T _{lead} ①	Lead Temperature			300	°C
R _{thJC}	Thermal Resistance, Junction to Case			1.0	K/W
R _{thJA} ②	Thermal Resistance, Junction to Ambient			80	
Wt	Weight		2.0		g
			0.07		(oz)

① 0.063 in. from Case (1.6mm) for 10 sec

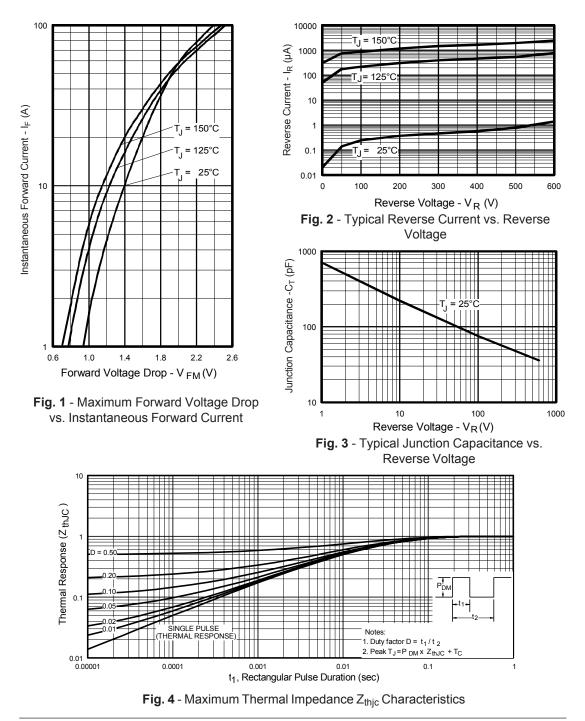
② Typical Socket Mount

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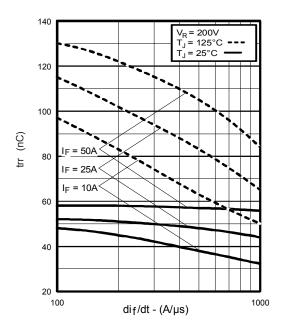


Fig. 5 - Typical Reverse Recovery vs. dif/dt

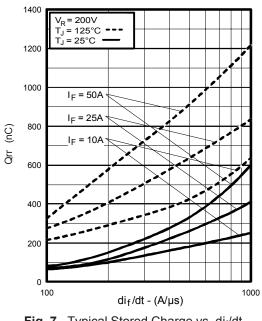


Fig. 7 - Typical Stored Charge vs. dif/dt



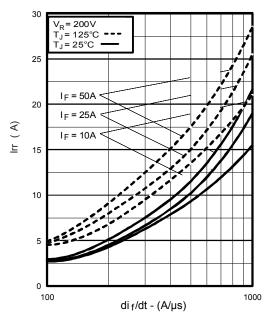


Fig. 6 - Typical Recovery Current vs. dif/dt

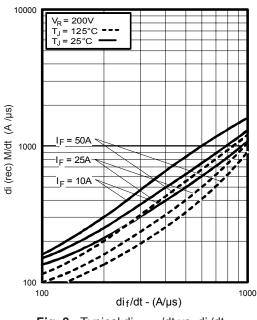


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt

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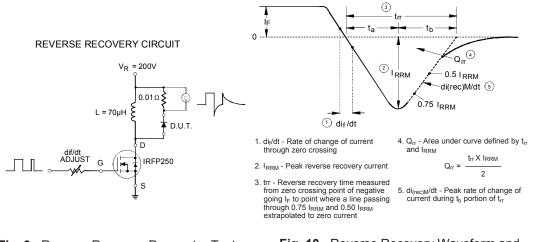
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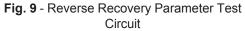
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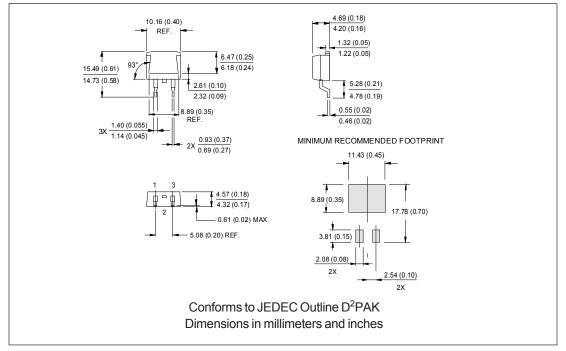




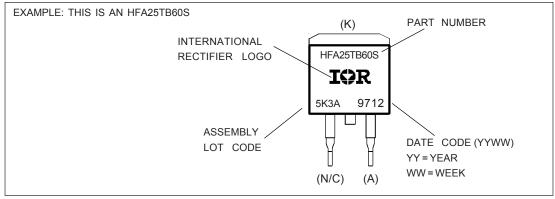
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Outline Table

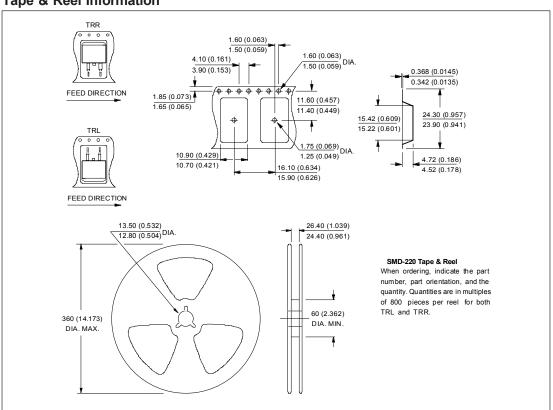


Part Marking Information



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Tape & Reel Information

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.

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